

### **GENERAL DESCRIPTION**

The HP4555 is a cost-effective, fully integrated high input voltage single-cell Li-ion battery charger. The charger uses a CC/CV charge profile required by Li-ion battery. The charger accepts an input voltage up to 24V but is disabled when the input voltage exceeds the OVP threshold, typically 6.8V, to prevent excessive power dissipation. The 24V rating eliminates the over-voltage protection circuit required in a low input voltage charger.

The charge current and the end-of-charge (EOC) current are programmable with external resistors. When the battery voltage is lower than 2.55V, the charger preconditions the battery with typically 20% of the programmed charge current. When the charge current reduces to the programmable EOC current level during the CV charge phase, the charging process is terminated, and meanwhile an EOC indication is provided by the  $\overline{\it CHG}$  pin, which is an open-drain output. An internal thermal foldback function protects the charger from any thermal failure. Two indication pins ( $\overline{\it PPR}$  and  $\overline{\it CHG}$ ) allow simple interface to a microprocessor or LEDs. When no adapter attached, the charger draws less than 1 $\mu$ A leakage current from the battery.

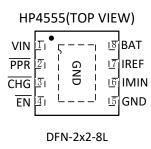
### **FEATURES**

- Complete Charger for Single-Cell-Li-ion or Polymer Batteries
- Integrated Pass Element and Current Sensor
- No External Blocking Diode Required
- Low Component Count and Cost
- Programmable Charger Current
- Programmable End-of-Charger Current
- Charge termination when charge current reduces to EOC Current
- Charger Current Thermal Foldback for Thermal Protection
- 2.55V Trickle Charge Threshold
- 6.8V Input Over-Voltage Protection
- 24V Maximum Voltage for the Power Input
- Power Presence and Charge Indications
- Less than 1µA Leakage Current from the Battery When No Input Power Attached
- Less than 200uA Supply Current when Charging is terminated
- Available in Green DFN-2x2-8L Packages

# **APPLICATIONS**

- Mobile Phones
- Blue-Tooth Devices
- PDAs
- MP3 Players
- Stand-Alone Chargers
- Other Handheld Devices

### **PIN ASSIGNMENT**





# **ORDER INFORMATION**

PART NO	PACAKGE	TEMPERATURE	TAPE & REEL
HP4555D8-42	DFN-2x2-8L	-40 ~ +85 ℃	4000/REEL
HP4555D8-43	DFN-2x2-8L	-40 ~ +85 ℃	4000/REEL
HP4555D8-435	DFN-2x2-8L	-40 ~ +85 ℃	4000/REEL
HP4555D8-44	DFN-2x2-8L	-40 ~ +85 ℃	4000/REEL

# **PART NUMBER RULES**

### HP4555 1 - 2

Code	Description
1	Package:
	D8: DFN-2x2-8L
2	Charge voltage:
	42/43/435/44: Battery
	charge voltage are
	4.2V/4.3V/4.35V/4.4V

# **MARKING DESCRIPTION:**

DFN-2x2-8L



"XXXX": Part number, here is "4555".

"XYWV": "X" stands for Internal Control Code, "Y" stands for Internal Control Code, "W" stands for the week of manufacturing, "V" stands for charge voltage.

### TYPICAL APPLICATION CIRCUIT

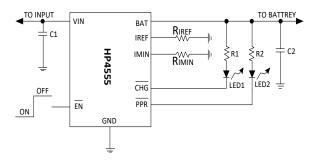


Figure 1.Typical application circuit interfacing to indication LEDs

### Component Description for Figure 1

PART	DESCRIPTION		
C1, C2	1μF X5R ceramic cap		
R <sub>IREF</sub>	24KΩ,1% for 500mA charge current		
R <sub>IMIN</sub>	270KΩ,1% for 40mA EOC current		
R1, R2	1ΚΩ, 5%		

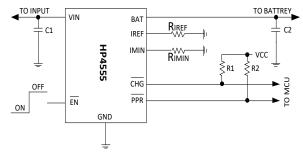


Figure 2.Typical application circuit with the indication signals interfacing to an MCU

### Component Description for Figure 2

•	
PART	DESCRIPTION
C1, C2	1μF X5R ceramic cap
R <sub>IREF</sub>	24KΩ,1% for 500mA charge current
R <sub>IMIN</sub>	270KΩ,1% for 40mA EOC current
R1, R2	100ΚΩ,5%

HP4555 Datasheet, 2019 V1.0 Hypower Microelectronics(Shanghai)Co., Ltd.



# **PIN DESCRIPTION**

PIN NO	SYMBOL	FUNCTION
1	VIN	Power Input. A $1\mu F$ or larger value X5R ceramic capacitor is recommended to be placed as close as possible to the input pin for decoupling purpose. Additional capacitance may be required to provide a stable input voltage.
2	PPR	Open-drain Power Presence Indication. The open-drain MOSFET turns on when the input voltage is above the POR threshold but below the OVP threshold, and turns off otherwise. This pin is capable of sinking 15mA (MIN) current to drive an LED. The maximum voltage rating for this pin is 5.5V. This pin is independent on the $\overline{EN}$ pin input.
3	СНG	Open-drain Charge Indication. This pin outputs a logic low when a charge cycle starts and turns to high impedance when the end-of-charge (EOC) condition is qualified. This pin is able to sink 15mA (MIN) current to drive an LED. When the charger is disabled, the $\overline{CHG}$ pin outputs high impedance.
4	EN	Enable Input. This is a logic input pin to disable or enable the charger. Drive high to disable the charger. When this pin is driven to low or left floating, the charger is enabled. This pin has an internal $200k\Omega$ pull-down resistor.
5	GND	System Ground.
6	IMIN	End-of-Charge (EOC) Current Programming Pin. Connect a resistor between this pin and the GND pin to set the EOC current. The EOC current $I_{\text{MIN}}$ can be programmed by the following equation: $I_{MIN} = \frac{9700}{R_{IMIN}} + 4 \ (mA)$ where $R_{\text{IMIN}}$ is in k $\Omega$ . The programmable range covers from 5mA to 120mA. EOC current will be influenced by battery internal impedance and results in a small drift. When programmed to less than 5mA, the accuracy is not guaranteed.
7	IREF	Charge-Current Programming and Monitoring Pin. Connect a resistor between this pin and the GND pin to set the charge current limit determined by the following equation: $I_{REF} = \frac{12000}{R_{IREF}} (mA)$ where $R_{IREF}$ is in $k\Omega$ . The resistor should be placed very close to this pin. The IREF pin voltage also monitors the actual charge current during the entire charge cycle, including the trickle, constant-current, and constant-voltage phases. When disabled, $V_{IREF} = 0V$ .
8	BAT	Charger Output Pin. Connect this pin to the battery. A $1\mu F$ or larger X5R ceramic capacitor is recommended for decoupling and stability purposes. When the $\overline{EN}$ pin is pulled to logic high, the BAT output is disabled.

# **ABSOLUTE MAXIMUM RATINGS (Note)**

SYMBOL	I	ITEMS		UNIT
V <sub>IN</sub>	Input Voltage		-0.3~27	V
	Voltage of other PINs	Voltage of other PINs		V
R <sub>θJA</sub>	Thermal Resistance	DFN-2x2-8L	118	℃/W
Tı	Junction Temperature	Junction Temperature		$^{\circ}$ C
T <sub>STG</sub>	Storage Temperature		-65 ~ +150	$^{\circ}$
T <sub>SOLDER</sub>	Package Lead Soldering Tem	Package Lead Soldering Temperature (10s)		$^{\circ}$ C
ESD MM	Machine Mode		200	V
ESD HBM	Human Body Mode		8	KV

**Note:** Exceed these limits to damage to the device. Exposure to absolute maximum rating conditions may affect device reliability.



### **RECOMMANDED OPERATING RANGE**

SYMBOL	ITEMS	VALUE	UNIT
V <sub>MAX</sub>	Maximum Supply Voltage	≤24	V
V <sub>IN</sub>	Operating Supply Voltage	4.55 to 6.10	V
I <sub>REF</sub>	Programmed Charge Current	20 to 700	mA
Торт	Operating Temperature	-40 to +85	$^{\circ}$

# **TYPICAL CHARGE PROFILE**

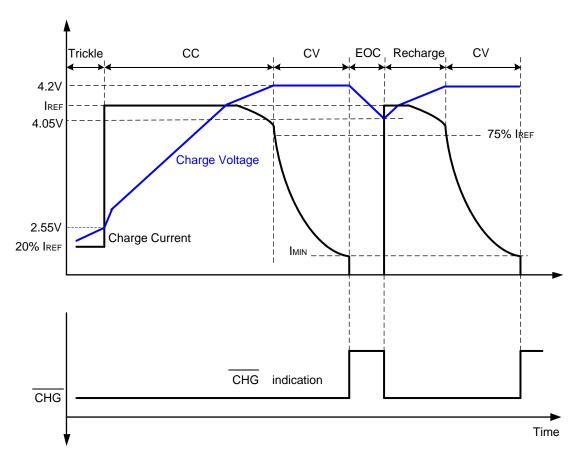


Figure 3. Typical Charge Profile



# **ELECTRICAL CHARACTERISTICS**

 $V_{IN}$ =5V,  $R_{IMIN}$ =243K $\Omega$ ,  $T_A$ =25 $^{\circ}$ C, unless otherwise noted.

Power-ON Reset	SYMBOL	ITEMS	CONDITIONS	MIN	TYP	MAX	UNIT
Viron   Falling POR Threshold   Indicate the comparator output.   3.1   3.6   3.9   V   Viv-Vux- Offset Voltage	Power-ON Re	eset		l			I
Var-Var Offset Voltage         Vos         Rising Edge         Valit = 4.5 V, Resus = 120 KΩ, use PPR to 10 80 100 150 mW           Vos         Falling Edge         Indicate the comparator output. (10 10 80 mW)           Over-Voltage Protection         Volve         OVP Threshold         Vext=4.5 V, Resus=120 KΩ, use PPR to 120 KQ, use PP	$V_{POR}$	Rising POR Threshold	$V_{BAT}=3.0V$ , $R_{IREF}=120K\Omega$ , use $\overline{PPR}$ to	3.4	3.9	4.2	V
No.	$V_{POR}$	Falling POR Threshold	indicate the comparator output.	3.1	3.6	3.9	V
Vos   Falling Edge	V <sub>IN</sub> -V <sub>BAT</sub> Offs	et Voltage		l			I
Over-Voltage Protection         Vovp         OVP Threshold         V <sub>BAT</sub> =4.5V, Ristr=120KΩ, use \$\bar{PPR}\$ to 100 to 170 250 300 mV           VOVPINS         OVP Threshold Hysteresis         V <sub>BAT</sub> =4.5V, Ristr=120KΩ, use \$\bar{PPR}\$ to 170 250 300 mV           Standby Current         Use Standby Mode VIN Pin Current V <sub>Res</sub> 5V, V <sub>BAT</sub> =4.5V, \$\bar{EN}\$ = I, R <sub>Ristr</sub> =120KΩ         135 200 µA           Janatisio         Standby Mode BAT Pin Current V <sub>Res</sub> 5V, V <sub>BAT</sub> =4.5V, \$\bar{EN}\$ = I, R <sub>Ristr</sub> =120KΩ         135 200 µA           Manation         Shutdown Current         V <sub>Res</sub> 5V, V <sub>BAT</sub> =4.5V, \$\bar{EN}\$ = I, R <sub>Ristr</sub> =120KΩ         135 200 µA           Janation         Shutdown Mode VIN Pin Current         V <sub>Res</sub> 5V, V <sub>Rat</sub> 1=4.5V, \$\bar{EN}\$ = I, R <sub>Ristr</sub> =120KΩ         130 200 µA           Janation         Shutdown Mode VIN Pin Current         V <sub>Res</sub> 5V, V <sub>Ristr</sub> =4.5V, V <sub>Ris</sub> 4.5V         2 92 µA           Janation         Shutdown Mode VIN Pin Current         V <sub>Res</sub> 24.5V, V <sub>Ris</sub> 4.3V         18 µA           Janation         UVLO Mode BAT Pin Current         V <sub>Res</sub> 45.5V, V <sub>Ris</sub> 4.3V         18 µA           Janation         UVLO Mode BAT Pin Current         V <sub>Ris</sub> 46.5V, V <sub>Ris</sub> 4.3V         1 µA           Steep Current         Input is floating or 0V         1 µA           Volutage Regulation         1 µA         1 µA           Volutage Regulation         1 µA         1 µA	Vos	Rising Edge	$V_{BAT}$ =4.5V, $R_{IREF}$ =120K $\Omega$ , use $\overline{PPR}$ to		100	150	mV
VovP	Vos	Falling Edge	indicate the comparator output.(1)	10	80		mV
Vour	Over-Voltage	e Protection		1			I
Standby Current   NonSTID	$V_{OVP}$	OVP Threshold	$V_{BAT}$ =4.5V, $R_{IREF}$ =120K $\Omega$ , use $\overline{PPR}$ to	6.5	6.80	7.1	V
IndigetorStandby Mode VIN Pin Current $V_{IN}$ =5V, $V_{BAT}$ =4.5V, $\overline{EN}$ = L, $R_{IREF}$ =120KΩ135200 $\mu$ A $I_{BATSTD}$ Standby Mode BAT Pin Current $V_{IN}$ =5V, $V_{BAT}$ =4.5V, $\overline{EN}$ = L, $R_{IREF}$ =120KΩ1.72 $\mu$ AShutdown Current $V_{IN}$ =5V, $V_{BAT}$ =4.5V, $V_{IN}$ =61.2V, $\overline{EN}$ = L, $R_{IREF}$ =120KΩ130200 $\mu$ A $I_{VINIOJS}$ Shutdown Mode VIN Pin Current $V_{IN}$ =5V, $R_{INEF}$ =120KΩ, Charger disabled130200 $\mu$ A $I_{VINIOJS}$ Shutdown Mode BAT Pin Current $V_{BAT}$ =4.5V, $V_{IN}$ =4.3V92 $\mu$ A $I_{IBATUVLO}$ UVLO Mode Supply Current $V_{IN}$ =4.5V, $V_{IN}$ =4.3V1.8 $\mu$ A $I_{IBATUVLO}$ UVLO Mode Supply Current $V_{IN}$ =70.6V88 $\mu$ A $I_{BATUVLO}$ UVLO Mode BAT Pin Current $V_{IN}$ =70.6V1 $\mu$ A $I_{BATSEEP}$ BAT Pin CurrentInput is floating or 0V1 $\mu$ A $V_{OUT}$ Output Voltage $I_{IREF}$ $I$	V <sub>OVPHYS</sub>	OVP Threshold Hysteresis	indicate the comparator output.	170	250	300	mV
Ranstro   Standby Mode BAT Pin Current   V <sub>IN</sub> =5V, V <sub>BAT</sub> =4.5V, \( \overline{EN} = L, R_{IREF}=120KΩ \)   1.7   2   μA     Shutdown Current   V <sub>INNOIS</sub>   Shutdown Mode VIN Pin Current   V <sub>INP</sub> =5V, R_{IREF}=120KΩ, Charger disabled   130   200   μA     V <sub>INNOIS</sub>   Shutdown Mode VIN Pin Current   V <sub>BAT</sub> =4.5V, V <sub>IN</sub> =4.3V   92   μA     V <sub>INNOIS</sub>   Shutdown Mode BAT Pin Current   V <sub>BAT</sub> =4.5V, V <sub>IN</sub> =4.3V   1.8   μA     V <sub>INNOIS</sub>   Shutdown Mode BAT Pin Current   V <sub>BAT</sub> =4.5V, V <sub>IN</sub> =4.3V   1.8   μA     V <sub>INNOIS</sub>   Shutdown Mode BAT Pin Current   V <sub>IN</sub> =4.5V, V <sub>IN</sub> =4.3V   1.8   μA     V <sub>INNOIS</sub>   U <sub>I</sub> VLO Mode Supply Current   V <sub>IN</sub> =4.3V   1.8   μA     V <sub>INNOIS</sub>   U <sub>I</sub> VLO Mode Supply Current   V <sub>IN</sub> =4.3V   1.8   μA     V <sub>INIOIS</sub>   U <sub>I</sub> VLO Mode BAT Pin Current   Input is floating or 0V   1   μA     V <sub>I</sub> VLOTE   SATE PIN Current   Input is floating or 0V   1   μA     V <sub>I</sub> VLOTE   Output Voltage   V <sub>I</sub> VLOTE   V <sub>I</sub> VLOTE	Standby Curr	rent		l			I
Shutdown Current   Shutdown Mode VIN Pin Current   VIN=5V, RINEF=120KΩ, Charger disabled   130   200   μA   VINNDS   Shutdown Mode VIN Pin Current   VIN=5V, RINEF=120KΩ, Charger disabled   130   200   μA   VINNDS   Shutdown Mode VIN Pin Current   VIN=5V, VIN=4.3V   92   μA   VINNDS   Shutdown Mode BAT Pin Current   VIN=4.5V, VIN=4.3V   1.8   μA   VINNDS   VINDDS   VI	I <sub>VINSTD</sub>	standby Mode VIN Pin Current	$V_{IN}$ =5V, $V_{BAT}$ =4.5V, $\overline{EN}$ = L, $R_{IREF}$ =120KΩ		135	200	μΑ
Numbus   Shutdown Mode VIN Pin Current   Vim=5V, Riber=120KΩ, Charger disabled   130   200   μA	I <sub>BATSTD</sub>	Standby Mode BAT Pin Current	$V_{IN}$ =5V, $V_{BAT}$ =4.5V, $\overline{EN}$ = L, $R_{IREF}$ =120KΩ		1.7	2	μΑ
VINNASO   Shutdown Mode VIN Pin Current   VBAT=4.5V, VIN=4.3V   92	Shutdown Cu	urrent		l			I
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>VINDIS</sub>	Shutdown Mode VIN Pin Current	V <sub>IN</sub> =5V, R <sub>IREF</sub> =120KΩ, Charger disabled		130	200	μΑ
VINDUVLO   UVLO Mode Supply Current   VINEVBATE 3.6V   88	I <sub>VINASD</sub>	Shutdown Mode VIN Pin Current	V <sub>BAT</sub> =4.5V, V <sub>IN</sub> =4.3V		92		μΑ
Indication   Indicating   I	I <sub>BATASD</sub>	Shutdown Mode BAT Pin Current	V <sub>BAT</sub> =4.5V, V <sub>IN</sub> =4.3V		1.8		μΑ
Sleep Current   I_BATSLEEP   BAT Pin Current   Input is floating or OV   1	I <sub>VINUVLO</sub>	UVLO Mode Supply Current	V <sub>IN</sub> =V <sub>BAT</sub> =3.6V		88		μΑ
Indicator         Imput is floating or OV         1         μA           Voltage Regulation           R <sub>IMIN</sub> =2MΩ, charge current=20mA         4.158         4.2         4.242         4.257         4.3         4.343         4.306         4.35         4.394         4.306         4.35         4.394         4.306         4.35         4.444         4.158         4.444         4.444         4.158         4.444         4.158         4.444         4.158         4.444         4.158         4.444         4.158         4.444         4.158         4.444         4.158         4.	I <sub>BATUVLO</sub>	UVLO Mode BAT Pin Current	V <sub>IN</sub> =V <sub>BAT</sub> =3.6V		1		μΑ
Voltage Regulation           Vour         Output Voltage $\frac{4.158}{4.2}$ $\frac{4.2}{4.257}$ $\frac{4.3}{4.3}$ $\frac{4.343}{4.343}$ $\frac{4.306}{4.356}$ $\frac{4.35}{4.3}$ $\frac{4.394}{4.356}$ $\frac{4.35}{4.4}$ $\frac{4.344}{4.444}$ R <sub>DS(ON)</sub> PMOS On Resistance         V <sub>BAT</sub> =3.8V, charge current=500mA, R <sub>IREF</sub> =10KΩ         1.2         Ω           Charge Current (2)           V <sub>IREF</sub> IREF Pin Output Voltage         V <sub>BAT</sub> =3.8V, R <sub>IREF</sub> =120KΩ         1.218         V           IREF         Constant Charge Current         R <sub>IREF</sub> =120KΩ, V <sub>BAT</sub> =2.8V to 3.8V         90         100         110         mA           I <sub>TIRK</sub> Trickle Charge Current         R <sub>IREF</sub> =120KΩ, V <sub>BAT</sub> =2.8V to 3.8V         90         100         110         mA           I <sub>TIRK</sub> Trickle Charge Current         R <sub>IREF</sub> =120KΩ, V <sub>BAT</sub> =2.4V         13         22         31         mA           I <sub>MIN</sub> =243KΩ         22         44         9         10         mA           Precondit	Sleep Curren	t	'	1			I .
$V_{OUT}$ Output Voltage $V_{BAT}=2M\Omega$ , charge current=20mA $V_{A.257}$ 4.3 4.343 4.344 4.306 4.35 4.394 4.356 4.4 4.444 4.356 4.4 4.444 4.356 A.7 4.366 A	I <sub>BATSLEEP</sub>	BAT Pin Current	Input is floating or OV			1	μΑ
$V_{OUT} = \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Voltage Regu	ulation		1			I.
$V_{OUT} = \begin{array}{c ccccccccccccccccccccccccccccccccccc$				4.158	4.2	4.242	V
$R_{DS(ON)}  PMOS \ On \ Resistance \qquad \begin{matrix} V_{BAT}=3.8V, \ charge \ current=500 \ mA, \\ R_{IREF}=10 \ K\Omega \end{matrix} \qquad $	.,	0		4.257	4.3	4.343	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V <sub>OUT</sub>	Output Voltage	RIMIN=2M11, charge current=20mA	4.306	4.35	4.394	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				4.356	4.4	4.444	
$\frac{R_{IREF} = 10K\Omega}{\DeltaV_{RECHRG}} \qquad \qquad$		DMOC On Desistance	V <sub>BAT</sub> =3.8V, charge current=500mA,		4.2		_
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	K <sub>DS(ON)</sub>	PIVIOS On Resistance	$R_{IREF}$ =10K $\Omega$		1.2		Ω
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\Delta$ V <sub>RECHRG</sub>	Auto Recharge Battery Voltage	V <sub>OUT</sub> - V <sub>BAT</sub>	100	150	200	mV
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Charge Curre	ent <sup>(2)</sup>					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$V_{IREF}$	IREF Pin Output Voltage	V <sub>BAT</sub> =3.8V, R <sub>IREF</sub> =120ΚΩ		1.218		V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>REF</sub>	Constant Charge Current	R <sub>IREF</sub> =120KΩ, V <sub>BAT</sub> =2.8V to 3.8V	90	100	110	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>TRK</sub>	Trickle Charge Current	R <sub>IREF</sub> =120KΩ, V <sub>BAT</sub> =2.4V	13	22	31	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		End of Chause Course	R <sub>IMIN</sub> =243KΩ	22	44	66	mA
Preconditioning Charge Threshold $R_{IRFF}$ =24.3K $\Omega$ 2.45 2.55 2.65 V	I <sub>MIN</sub>	End-or-Charge Current	R <sub>IMIN</sub> =2MΩ	4	9	14	mA
$V_{MIN}$   $R_{IRFF} = 24.3 \text{ K}\Omega$   2.45   2.55   2.65   V	Precondition	ing Charge Threshold					
V <sub>MIN</sub> Voltage   K <sub>IREF</sub> =24.3KΩ   2.45   2.55   2.65   V	\/	Preconditioning Charge Threshold	B -24.2VO	2.45	2 5 5	2.65	V
	<b>V</b> <sub>MIN</sub>	Voltage	K <sub>IREF</sub> =24.3K\1	2.45	2.55	2.65	\ \ \



# High Input Voltage Charger with OVP Protection and Charge Termination

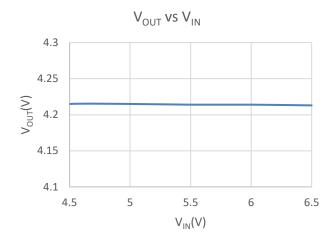
$V_{MINHYS}$	Preconditioning Voltage Hysteresis	$R_{IREF}$ =24.3K $\Omega$	70	100	130	mV
Internal Tem	perature Monitoring					
T <sub>FOLD</sub>	Charge Current Foldback Threshold			115		$^{\circ}$ C
Logic input a	and outputs					
V <sub>EN_H</sub>	$\overline{EN}$ Pin Logic Input High		1.5			V
V <sub>EN_L</sub>	$\overline{EN}$ Pin Logic Input Low				0.8	V
R <sub>EN</sub>	$\overline{EN}$ Pin Internal Pull Down Resistance		150	200	250	ΚΩ
I <sub>CHG_sink</sub>	₹ Sink Current when LOW	Pin Voltage = 1V	10	18		mA
ICHG_leakage	<i>CHG</i> Leakage Current when High Impedance	V <sub>CHG</sub> = 5.5V			20	μΑ
IPPR_sink	PPR Sink Current when LOW	Pin Voltage = 1V	10	18		mA
IPPR_leakage	PPR Leakage Current when High Impedance	V <sub>PPR</sub> = 5.5V			20	μΑ

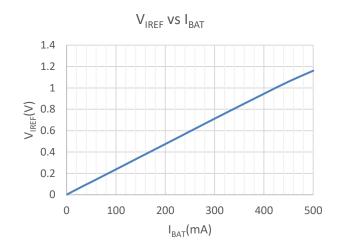
### Note:

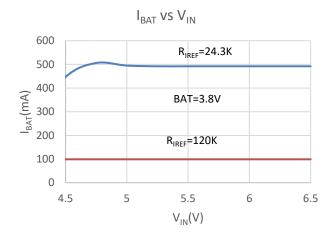
- 1. The 4.5V  $V_{BAT}$  is selected so that the  $\overline{PPR}$  output can be used as the indication for the offset comparator output indication. If the  $V_{BAT}$  is lower than the POR threshold, no output pin can be used for indication.
- 2. The charge current can be affected by the thermal foldback function if the IC under the test setup cannot dissipate the heat.

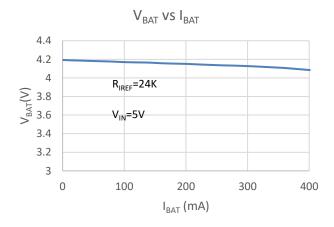


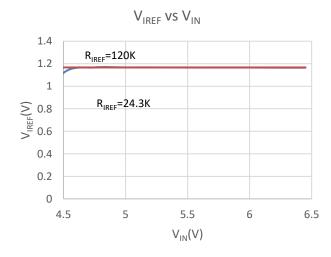
### TYPICAL PERFORMANCE CHARACTERISTICS

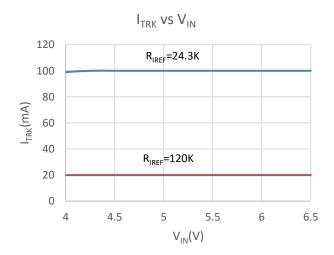




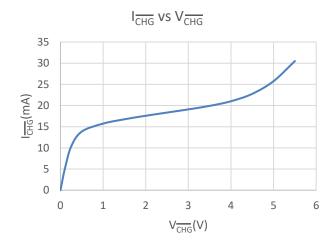


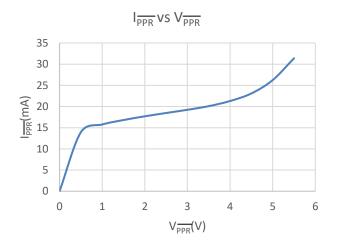


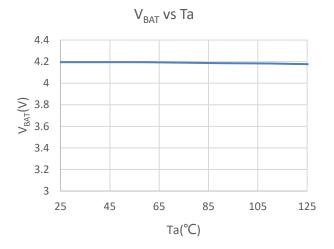


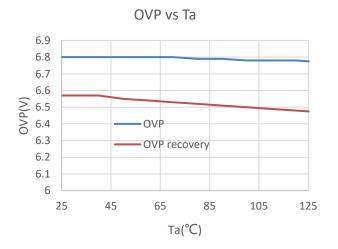


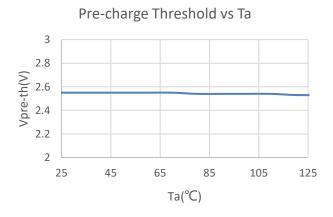


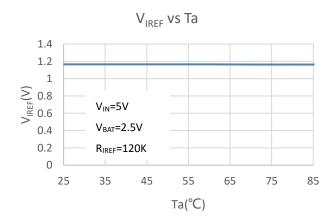




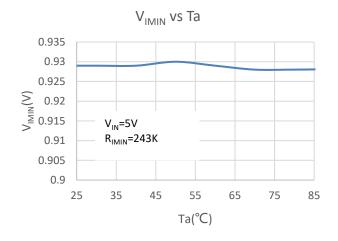


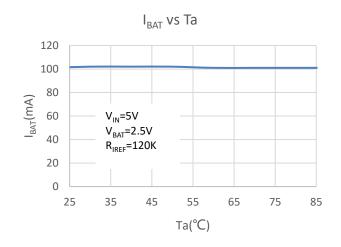


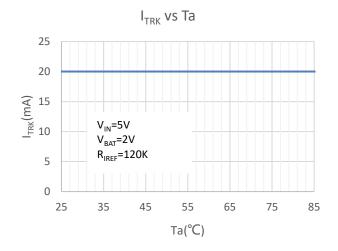


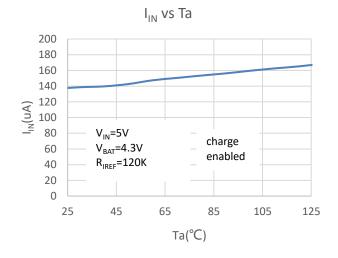


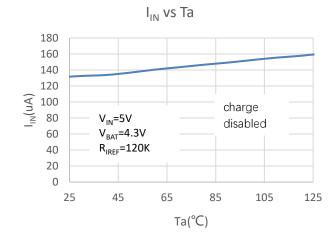


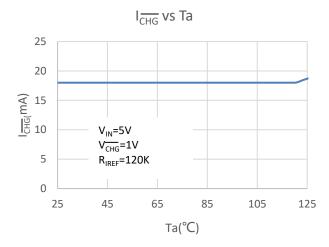




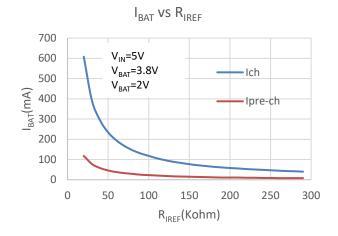


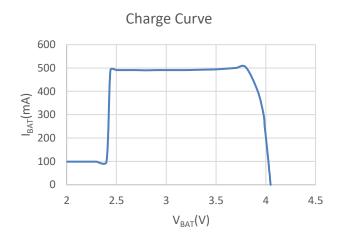


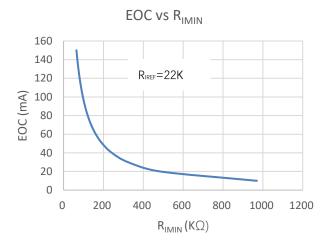


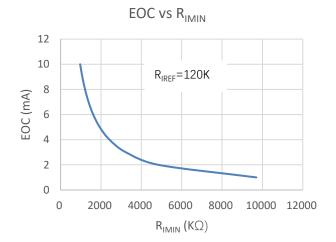














### **OVP Test**



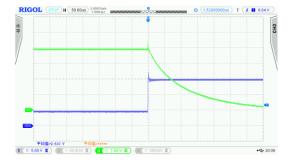
# 

### V<sub>IN</sub>=0V to 20V

平均值=4.787 V 平均值===== 1 = 5.00 V X 2 ~ 50 0mV X 2 = 1.00 V X 4 (= 500mV X



### V<sub>IN</sub>=5V to 15V



### CH3:V<sub>BAT</sub>

### V<sub>IN</sub>=0V to 15V



### $V_{IN}$ =5V to 10V



### V<sub>IN</sub>=5V to 20V





### **OPERATION**

The HP4555 charges a Li-ion battery using a CC/CV profile. The constant current IREF is set with the external resistor RIREF (see Figure 1) and the constant voltage is fixed at 4.2V (or 4.3V, or 4.35V, or 4.4V). If the battery voltage is below a typical 2.55V trickle charge threshold, the HP4555 charges the battery with a trickle current of 20% of IREF until the battery voltage rises above the trickle charge threshold. Fast charge CC mode is maintained at the rate determined by programming IREF until the cell voltage rises to 4.2V (or 4.3V, or 4.35V, or 4.4V). When the battery voltage reaches 4.2V (or 4.3V, or 4.35V, or 4.4V), the charger enters a CV mode and regulates the battery voltage at 4.2V (or 4.3V, or 4.35V, or 4.4V) to fully charge the battery without the risk of over charge. Upon reaching an end-of-charge (EOC) current, the charger indicates the charge completion with the  $\overline{CHG}$  pin and terminate the charge current. Figure 3 shows the typical charge waveforms after the power is on.

The EOC current level  $I_{MIN}$  is programmable with the external resistor  $R_{IMIN}$  (see Figure 1). The  $\overline{CHG}$  pin turns to low when the trickle charge starts and rises to high impedance at the EOC. The  $\overline{CHG}$  pin to turn on again when the battery voltage lower than 150mV (typically) of output voltage after the EOC is reached, and then the recharge process is beginning.

A thermal foldback function reduces the charge current anytime when the die temperature reaches typically  $115~^{\circ}\mathrm{C}$ . This function guarantees safe operation when the printed circuit board (PCB) is not capable of dissipating the heat generated by the linear charger. The HP4555 accepts an input voltage up to 24V but disables charging when the input voltage exceeds the OVP threshold, typically 6.8V for HP4555, to protect against unqualified or faulty AC adapters.

### PPR Indication

The  $\overline{PPR}$  pin is an open-drain output to indicate the presence of the AC adapter. Whenever the input

voltage is higher than the POR threshold, the  $\overline{PPR}$  pin turns on the internal open-drain MOSFET to indicate a logic low signal, independent on the  $\overline{EN}$  pin input. When the internal open-drain FET is turned off, the  $\overline{PPR}$  pin leaks less than 20µA current. When turned on, the  $\overline{PPR}$  pin is able to sink at least 10mA current under all operating conditions. The  $\overline{PPR}$  pin can be used to drive an LED (see Figure 1) or to interface with a micro-processor.

# **Power Good Range**

The power good range is defined by the following three conditions:

- 1.  $V_{IN} > V_{POR}$
- 2.  $V_{IN} V_{BAT} > V_{OS}$
- $3. V_{IN} < V_{OVP}$

where the  $V_{OS}$  is the offset voltage for the input and output voltage comparator, discussed shortly, and the  $V_{OVP}$  is the over-voltage protection threshold given in the Electrical Characteristics table. All  $V_{POR}$ ,  $V_{OS}$ , and  $V_{OVP}$  have hysteresis, as given in the Electrical Characteristics table. The charger will not charge the battery if the input voltage is not in the power good range.

### **Input and Output Comparator**

The charger will not be enabled unless the input voltage is higher than the battery voltage by an offset voltage V<sub>OS</sub>. The purpose of this comparator is to ensure that the charger is turned off when the input power is removed from the charger. Without this comparator, it is possible that the charger will fail to power down when the input is removed and the current can leak through the PFET pass element to continue biasing the POR and the Pre-Regulator blocks.



### **Dropout Voltage**

The constant current may not be maintained due to the  $R_{DS\,(ON)}$  limit at a low input voltage. The worst case  $R_{DS\,(ON)}$  is at the maximum allowable operating temperature.

### CHG Indication

The  $\overline{CHG}$  is an open-drain output capable of sinking at least 10mA current when the charger starts to charge, and turns off when the EOC current is reached. The  $\overline{CHG}$  signal is interfaced either with a microprocessor GPIO or an LED for indication.

# EN Input

 $\overline{EN}$  is an active-low logic input to enable the charger. Drive the  $\overline{EN}$  pin to low or leave it floating to enable the charger. This pin has a 200k $\Omega$  internal pull-down resistor so when left floating, the input is equivalent to logic low. Drive this pin to high to disable the charger. The threshold for high is given in the Electrical Characteristics table.

### **IREF Pin**

The IREF pin has the two functions as described in the Pin Description section. When setting the fast charge

current, the charge current is guaranteed to have 10% accuracy with the charge current set at 100mA. When monitoring the charge current, the accuracy of the IREF pin voltage vs. the actual charge current has the same accuracy as the gain from the IREF pin current to the actual charge current.

### Operation without the Battery

The HP4555 relies on a battery for stability and works under LDO mode if the battery is not connected. With a battery, the charger will be stable with an output ceramic decoupling capacitor in the range of  $1\mu F$  to  $220\mu F$ . In LDO mode, its stability depends on load current,  $C_{OUT}$ , etc. The maximum load current is limited by the dropout voltage 4.2V, the programmed IREF and the thermal foldback. If no load, the output voltage is rippled between recharge voltage and terminated voltage, and the  $\overline{CHG}$  pin is pulled low or in high impedance periodically. The frequency of this period influenced by output capacitance. So, the output voltage is stable only with a load current more than termination current that is set by IMIN pin.

### Thermal Foldback

The thermal foldback function starts to reduce the charge current when the internal temperature reaches a typical value of  $115^{\circ}$ C.



### **APPLICATION INFORMATION**

### **Input Capacitor Selection**

The input capacitor is required to suppress the power supply transient response during transitions. Mainly this capacitor is selected to avoid oscillation during the start up when the input supply is passing the POR threshold and the VIN-BAT comparator offset voltage. When the battery voltage is above the POR threshold, the  $V_{\text{IN}}$  -  $V_{\text{BAT}}$  offset voltage dominates the hysteresis value. Typically, a 1µF X5R ceramic capacitor should be sufficient to suppress the power supply noise.

### **Output Capacitor Selection**

The criterion for selecting the output capacitor is to maintain the stability of the charger as well as to bypass any transient load current. The minimum capacitance is a  $1\mu F$  X5R ceramic capacitor. The actual capacitance connected to the output is dependent on the actual application requirement.

### **Layout Guidance**

The HP4555 uses thermally-enhanced DFN packages that have an exposed thermal pad at the bottom side of the packages. The layout should connect as much as possible to copper on the exposed pad. Typically, the component layer is more effective in dissipating heat. The thermal impedance can be further reduced by using other layers of copper connecting to the exposed pad through a thermal via array. Each thermal via is recommended to have 0.3mm diameter and 1mm distance away from other thermal vias.

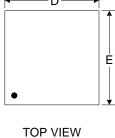
### **Input Power Sources**

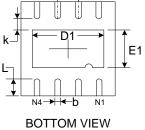
The input power source is typically a well-regulated wall cube with 1-meter length wire or a USB port. The HP4555 can withstand up to 24V on the input without damaging the IC. If the input voltage is higher than typically 6.8V, the charger stops charging.

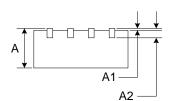


# **PACKAGE OUTLINE**

Package	DFN-2x2-8L	Devices per reel	4000pcs	Unit	mm
Package Dime	ension:				
	<del> </del>	D	N5   <mark>←</mark>	8	
		<u> </u>	<b>\</b>		







SIDE VIEW

Courselle and	Dimensions in Millimeters		Dimension	s in Inches
Symbol	Min	Max	Min	Max
Α	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203	3 REF	0.008	3 REF
D	1.900	2.100	0.075	0.083
D1	1.100	1.300	0.043	0.051
Е	1.900	2.100	0.075	0.083
E1	0.500	0.700	0.020	0.028
b	0.180	0.300	0.007	0.012
е	0.500 TYP		0.020 TYP	
k	0.200 MIN		0.008	MIN
L	0.250	0.450	0.010	0.018

HP4555 Datasheet, 2019 V1.0 Hypower Microelectronics(Shanghai)Co., Ltd.



# **REVISION HISTORY**

Version No.	Date	Description
Preliminary	2018-09-08	- Initial preliminary release
V0.1	2018-09-30	- Update typical performance characteristics
V0.2	2018-10-15	- Update Order Information
	2019 10 20	- Update description of IMIN and IREF
V0.3	2018-10-30	- Update electric parameters
V0.4	2019-01-25	- Add 4.4V charge voltage
V0.5	2019-06-24	- Add programmed charge current
V 1.0	2019-12-02	- Update marking description

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HP4059D6-44Y HP2601D8-68 CM1124-EAC ME4064AM5G-N ME4084AM5G ME4084BN8BG ME4074CM5G RY2231B1D4
FM5324GA FM4057E42 TP4054 TP4056 TP4054S5-2 WST4054 WSP4056 AP5056SPER FH8209 FH8614G1 FH8206 FH8210A
XB7608AJ LR4054-T ME4312CSG PJ4054B BRCL3230BME